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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/428,052	10/27/1999	KIYOSHI IRINO	970901A	4139	
23850 7	590 02/27/2003				
ARMSTRON	ARMSTRONG,WESTERMAN & HATTORI, LLP			EXAMINER	
1725 K STREET, NW SUITE 1000			DIAZ, JOSE R		
	WASHINGTON, DC 20006			<del></del>	
	,		ART UNIT	PAPER NUMBER	
			2815		
			DATE MAILED: 02/27/2003	DATE MAILED: 02/27/2003	

Please find below and/or attached an Office communication concerning this application or proceeding.

PTO-90C (Rev. 07-01)

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Office Action Summary		Applicati n No.	Applicant(s)
		09/428,052	IRINO, KIYOSHI
		Examiner	Art Unit
		José R Díaz	2815
Period fo	The MAILING DATE of this communication app	pears on the cover sheet v	rith the correspondence address
A SH THE I - Exter after - If the - If NO - Failu - Any I	ORTENED STATUTORY PERIOD FOR REPLIMAILING DATE OF THIS COMMUNICATION. Insions of time may be available under the provisions of 37 CFR 1.1 SIX (6) MONTHS from the mailing date of this communication. It is period for reply specified above is less than thirty (30) days, a replication of the provision of the provis	136(a). In no event, however, may a ly within the statutory minimum of thi will apply and will expire SIX (6) MO e, cause the application to become A	reply be timely filed  rty (30) days will be considered timely.  NTHS from the mailing date of this communication.  BANDONED (35 U.S.C. § 133).
1)[	Responsive to communication(s) filed on 13 l	December 2002 .	
2a)□	This action is <b>FINAL</b> . 2b)⊠ Th	nis action is non-final.	
3)	Since this application is in condition for allows closed in accordance with the practice under		
	ion of Claims		
•	Claim(s) <u>6,10-12,15 and 16</u> is/are pending in		
_	4a) Of the above claim(s) is/are withdra	wn from consideration.	
5)⊠	Claim(s) <u>6,15 and 16</u> is/are allowed.		
•	Claim(s) <u>10-12</u> is/are rejected.		
-	Claim(s) is/are objected to.		
	Claim(s) are subject to restriction and/c ion Papers	or election requirement.	
9)	The specification is objected to by the Examine	er.	
10)	The drawing(s) filed on is/are: a)☐ acce	pted or b) objected to by	the Examiner.
	Applicant may not request that any objection to th		
11)	The proposed drawing correction filed on	_ is: a) ☐ approved b) ☐	disapproved by the Examiner.
	If approved, corrected drawings are required in re		
12) 🔲	The oath or declaration is objected to by the Ex	kaminer.	
	under 35 U.S.C. §§ 119 and 120		
13)⊠	Acknowledgment is made of a claim for foreign	n priority under 35 U.S.C.	§ 119(a)-(d) or (f).
a)	☑ All b)☐ Some * c)☐ None of:		
	1. Certified copies of the priority document		
	2. Certified copies of the priority document		
* 5	3. Copies of the certified copies of the prio application from the International Bu See the attached detailed Office action for a list	ireau (PCT Rule 17.2(a)).	
14) 🗌 <i>A</i>	Acknowledgment is made of a claim for domest	ic priority under 35 U.S.C	. § 119(e) (to a provisional application).
	a)  The translation of the foreign language pro Acknowledgment is made of a claim for domest		
Attachmen	•	· •	
2) Notic	ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice o	Summary (PTO-413) Paper No(s) Informal Patent Application (PTO-152)

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#### **DETAILED ACTION**

#### Continued Examination Under 37 CFR 1.114

➤ A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on December 13, 2002 has been entered.

## Claim Objections

Claim 12 is objected to under 37 CFR 1.75(c), as being of improper dependent form for failing to further limit the subject matter of a previous claim. Applicant is required to cancel the claim(s), or amend the claim(s) to place the claim(s) in proper dependent form, or rewrite the claim(s) in independent form. Claim 12 does not further limit claim 10 because the limitation recited in claim 12 was incorporated in the amended claim 10.

### Claim Rejections - 35 USC § 102

> The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

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➤ Claims 10-12 are rejected under 35 U.S.C. 102(e) as being anticipated by Pan (US Pat. No. 5,750,435).

Regarding claims 10 and 12, Pan teaches a method for manufacturing a semiconductor device (see cols. 1-10) comprising: forming a gate oxide film on a substrate; forming a gate electrode pattern, forming diffusion regions; implanting N atoms after the step of forming the diffusion regions (see col. 6, lines 6-15 and col. 10, lines 5-25), wherein said implantation step is conducted with a dose of, for example, 1E14 cm<sup>-2</sup> (see col. 6, lines 12-14).

Regarding claim 11, Pan teaches energy of, for example, 5 keV (see col. 6, lines 14-15).

## Allowable Subject Matter

> Claims 6 and 15-16 are allowed.

## Response to Arguments

➤ Applicant's arguments filed December 13, 2002 have been fully considered but they are not persuasive. Applicant argues that the reference Pan does not anticipates the claimed invention since Pan fails to teach the claimed ranges of ion implantation dose and implantation energy. However, the Examiner disagrees. With regards to the dose concentration, Applicant clearly pointed out that the invention is not limited to only a dose concentration of 1-3 X 10<sup>14</sup> cm<sup>-2</sup> (see page 14 lines 8-12 of Applicant's Specification). As a matter of fact, such a claimed dose range is not a critical range, but merely an example provided by Applicant (please note the use of the terms "For example" and "may be" on page 14, lines 8 and 10, respectively). Thus, the

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reference Pan anticipates the claimed limitation since Pan teaches an ion dose of, for example, 1 X 10 <sup>14</sup> cm<sup>-2</sup> (see col. 6, lines 12-13), which lies within the claimed dose range and achieves the result of incorporating N atoms in the gate oxide, which is the same result disclosed by Applicant. Further, the Federal Circuit has stated that in the case where the claimed ranges "overlap or lie inside ranges disclosed by the prior art" a *prima facie* case of obviousness exists. *In re* Wertheim, 541 F.2d 257, 191 USPQ 90 (CCPA 1976); *In re* Woodruff, 919 F.2d 1575, 16 USPQ2d 1934 (Fed. Cir. 1990). Therefore, the references Pan anticipates the claimed limitation since first, the claimed dose range is not a critical range because Applicant fails to show that the claimed range achieves unexpected results relative to the prior art range, and second, Pan teaches an ion dose, which lies within the claimed dose range.

With regards to the implantation energy, Applicant states that what is critical for the invention is the step of setting the acceleration voltage (see page 14, lines 6-8 of Applicant's Specification). For example, Applicant states that by setting the acceleration voltage to 100 KeV or less the N+ atoms do not reach the substrate (see page 14, lines 9 of Applicant's Specification). Pan clearly teaches such a critical step in column 6, lines 13-15, wherein Pan discloses an acceleration voltage of less than 100 KeV. Therefore, the reference Pan anticipates the claimed limitation since Pan teaches the critical step of an acceleration voltage of less than 100 keV. As such the rejection is considered to be proper.

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## Correspondence

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Any inquiry concerning this communication or earlier communications from the examiner should be directed to José R Díaz whose telephone number is (703) 308-6078. The examiner can normally be reached on 9:00-5:00 Monday, Tuesday, Thursday and Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie Lee can be reached on (703) 308-1690. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 308-7722 for regular communications and (703) 746-3891 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

JRD February 24, 2003

EDDIE LEE

SUPERVISORY PATENT EXAMINER TECHNOLOGY CENTER 2800